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DATE MAILED: 07/26/2004

APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/726,392	12/02/2003	Hiromichi Kumakura	31904-3	5617
7590 07/26/2004			EXAMINER	
Mitchell P. Brook, Esq.			WARREN, MATTHEW E	
LUCE, FORWARD, HAMILTON & SCRIPPS LLP Suite 200			ART UNIT	PAPER NUMBER
11988 El Camino Real			2815	
San Diego, CA 92130			DATE MAILED: 07/26/200	4

Please find below and/or attached an Office communication concerning this application or proceeding.

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		Application No.	Applicant(s)				
Office Action Summary		10/726,392	KUMAKURA ET AL.				
		Examiner	Art Unit				
		Matthew E Warren	2815				
Period fo	The MAILING DATE of this communication approximation of the second section approximation approxim	ppears on the cover sheet	with the correspondence addres	;s			
THE - Exte after - If the - If NC - Failu Any	ORTENED STATUTORY PERIOD FOR REP MAILING DATE OF THIS COMMUNICATION nsions of time may be available under the provisions of 37 CFR 1 SIX (6) MONTHS from the mailing date of this communication, period for reply specified above is less than thirty (30) days, a reprivation of the present of the maximum statutory perions to reply within the set or extended period for reply will, by staturely received by the Office later than three months after the mailed patent term adjustment. See 37 CFR 1.704(b).	.136(a). In no event, however, ma pply within the statutory minimum of d will apply and will expire SIX (6) N tte, cause the application to becom	va reply be timely filed thirty (30) days will be considered timely. IONTHS from the mailing date of this commus BABANDONED (35 U.S.C. § 133).	unication.			
Status							
1) ズ	Responsive to communication(s) filed on 24	April 2004.					
2a)□	This action is FINAL . 2b)⊠ This action is non-final.						
3)	Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.						
Disposit	ion of Claims						
5)□ 6)⊠ 7)□	Claim(s) 1-7 and 14-21 is/are pending in the 4a) Of the above claim(s) is/are withdred Claim(s) is/are allowed. Claim(s) 1-3,5-7,14-16 and 18-21 is/are rejected to. Claim(s) is/are objected to. Claim(s) are subject to restriction and	awn from consideration.					
Applicat	ion Papers						
	The specification is objected to by the Examin						
10)	10) ☐ The drawing(s) filed on is/are: a) ☐ accepted or b) ☐ objected to by the Examiner.						
	Applicant may not request that any objection to the						
11)	Replacement drawing sheet(s) including the correct The oath or declaration is objected to by the						
Priority :	under 35 U.S.C. § 119						
a)	Acknowledgment is made of a claim for foreign All b) Some * c) None of: 1. Certified copies of the priority docume 2. Certified copies of the priority docume 3. Copies of the certified copies of the priority docume application from the International Bure See the attached detailed Office action for a limit	nts have been received. nts have been received i iority documents have be eau (PCT Rule 17.2(a)).	n Application No een received in this National Sta	ge			
Attachmer	ut(s) ce of References Cited (PTO-892)	4) ☐ Intervi	ew Summary (PTO-413)				
2) Notice 3) Information	ce of Keretences Cited (FTO-032) ce of Draftsperson's Patent Drawing Review (PTO-948) mation Disclosure Statement(s) (PTO-1449 or PTO/SB/0 er No(s)/Mail Date 12/2/03.	Paper	No(s)/Mail Date of Informal Patent Application (PTO-15	2)			

DETAILED ACTION

This Office Action is in response to the Election filed on April 24, 2004.

Election/Restrictions

Applicant's election of Group II, claims 1-7 and 14-21 in the reply filed on April 24, 2004 is acknowledged. Because applicant did not distinctly and specifically point out the supposed errors in the restriction requirement, the election has been treated as an election without traverse (MPEP § 818.03(a)).

Specification

The title of the invention is not descriptive. A new title is required that is clearly indicative of the invention to which the claims are directed.

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claims 1-3, 6, and 7 are rejected under 35 U.S.C. 103(a) as being unpatentable over the Applicant's Prior Art Figure 2 (APAF 2) in view of Aoi (US 6,197,696 B1).

The APAF 2 shows a semiconductor device comprising: a semiconductor base (103), a first insulation film (109) which is provided on said semiconductor base and is

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made of a silicon material, a second insulation film (108) which is provided on said first insulation film, is made of an organic material and is thicker than said first insulation film. A wiring layer (107) is provided on said second insulation film, wherein a current flows between said wiring layer and an external terminal (106). The APAF shows all of the elements of the claims except the third insulation film on the second insulation film. Aoi shows (fig. 3c) a semiconductor device comprising: a semiconductor base (100), a first insulation film (102A) which is provided on said semiconductor base and is made of a silicon material, a second insulation film (103A) which is provided on said first insulation film, is made of an organic material and is thicker than said first insulation film. A third insulation film (104A), which is provided on said second insulation film, is made of a silicon material and is thinner than said second insulation film (col. 10, lines 29-54). The third insulation film is used to improve the adhesion of the organic film and the wiring layer (col. 12, lines 12-22). Therefore it would have been obvious to one of ordinary skill in the art at the time the invention was made to modify the insulating structure of the APAF 2 by adding a third insulating layer as taught by Aoi to improve the adhesion of the underlying organic film and subsequent wiring layer.

In re claim 2, Aoi shows (fig. 3c) a fourth insulation film (105A) is provided between said third insulation film and said wiring layer so as to cover an entire surface of said third insulation film and is made of an organic material (col. 10, lines 40-45).

In re claim 3, Aoi discloses (col. 12, lines 8-11) that a fifth insulation film is provided between said fourth insulation film and said wiring layer and is made of a silicon material because the metal levels and interlayer dielectrics can be repeated.

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In re claim 6, the APAF 2 discloses that said wiring layer is made of metal.

In re claim 7, the APAF 2 shows that said wiring layer constitutes a metal pad (107) which is connected to said external terminal (106), and/or a metal wire through which the current flows via said metal pad.

Claim 5 is rejected under 35 U.S.C. 103(a) as being unpatentable over the Applicant's Prior Art Figure 2 (APAF 2) in view of Aoi (US 6,197,696 B1) as applied to claims 1 and 2 above, and further in view of Noda (JP 2001-177115 A).

In re claim 5, neither reference discloses that said fourth insulation film is made of polybenzoxazole resin. Noda discloses (abstract) that an organic material may be formed of polybenzoxazole resin to form a reliable semiconductor device. Therefore, it would have been obvious to one of ordinary skill in the art at the time the invention was made to modify the organic material of the APAF 2 and Aoi by using polybenzoxazole resin as taught by Noda to provide a highly reliable semiconductor device.

Claims 14-16, 18, 20, and 21 are rejected under 35 U.S.C. 103(a) as being unpatentable over the Applicant's Prior Art Figure 2 (APAF) in view of Lin (US 6,657,310 B2).

The APAF 2 shows a semiconductor device comprising: a semiconductor base (103), a first insulation film (109) which is provided on said semiconductor base and is made of a silicon material, a second insulation film (108) which is provided on said first insulation film, is made of an organic material and is thicker than said first insulation

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film. A wiring layer (107) is provided on said second insulation film, wherein a current flows between said wiring layer and an external terminal (106). The APAF shows all of the elements of the claims except the third insulation film on the second insulation film wherein the third insulation film has a moisture resistant property. Lin shows (fig. 2) a semiconductor device having first and second (2 and 3) lower insulation films. A third insulation film (4) of silicon nitride, having a moisture resistance property, is formed on those films to provide protection from moisture and contamination. Therefore, it would have been obvious to one of ordinary skill in the art at the time the invention was made to modify the insulation structure of the APAF 2 by adding a third insulation layer having a moisture resistance property as taught by Lin to provide protection from moisture and contamination.

In re claim 15, Lin shows (fig. 2) that a fourth insulation film (film within layer 3 and beneath film 4) is provided between said third insulation film and said wiring layer so as to cover an entire surface of said third insulation film in order to prevent said third insulation film from being damaged.

In re claim 16, Lin shows (fig. 2) the device further comprising a fifth insulation film (5) which is provided between said fourth insulation film (3) and a wiring layer (10) but does not specifically discloses that it functions as an adhesive layer for preventing separation of said wiring layer. However, because the materials and structure is the same as the instant invention, the fifth insulation layer of Lin inherently functions as an adhesive layer.

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In re claim 18, Lin (fig. 2) does not specifically disclose that said fourth insulation film functions as an adhesive layer for preventing separation of said wiring layer.

However, because the materials and structure is the same as the instant invention, the fourth insulation layer of Lin inherently functions as an adhesive layer.

In re claim 20, the APAF 2 discloses that said wiring layer is made of metal.

In re claim 21, the APAF 2 shows that said wiring layer constitutes a metal pad (107) which is connected to said external terminal (106), and/or a metal wire through which the current flows via said metal pad.

Claim 19 is rejected under 35 U.S.C. 103(a) as being unpatentable over the Applicant's Prior Art Figure 2 (APAF) in view of Lin (US 6,657,310 B2) as applied to claims, 14, 15, and 18 above, and further in view of Noda (JP 2001-177115 A).

In re claim 5, neither reference discloses that said fourth insulation film is made of polybenzoxazole resin. Noda discloses (abstract) that an organic material may be formed of polybenzoxazole resin to form a reliable semiconductor device. Therefore, it would have been obvious to one of ordinary skill in the art at the time the invention was made to modify the organic material of the APAF 2 and Lin by using polybenzoxazole resin as taught by Noda to provide a highly reliable semiconductor device.

Allowable Subject Matter

Claims 4 and 7 are objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.

Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Matthew E Warren whose telephone number is (571) 272-1737. The examiner can normally be reached on Mon-Thur and alternating Fri 9:00-5:00pm.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Tom Thomas can be reached on (571) 272-1664. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should

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you have questions on access to the Private PAIR system, contact the Electronic

Business Center (EBC) at 866-217-9197 (toll-free).

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July 22, 2004

TOM THOMAS

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